TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT4S03A

VHF~UHF Band Low Noise Amplifier Applications

• Low noise figure: NF = 1.4dB (f = 2 GHz)

• High gain: Gain = 9dB (f = 2 GHz)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	10	$\mathcal{M}($
Collector-emitter voltage	V _{CEO}	5	V
Emitter-base voltage	V _{EBO}	2	(\sqrt{y})
Base current	Ic	40	mA
Collector current	Ι _Β	10	mΑ
Collector power dissipation	PC	1/50	> mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	55~125	ွဲပ

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Weight: 0.012 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T (1)	$V_{CE} = 1 V$, $I_C = 5 mA$	2	4.5	_	GHz
	f _T (2)	$V_{CE} = 3 \text{ V, } I_{C} = 10 \text{ mA}$	7	10	_	
Insertion gain	S _{21e} ² (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$	3.5	5.5	_	dB
	S _{21e} ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 20 \text{ mA}, f = 2 \text{ GHz}$	7	9	_	
Noise figure`	NF (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$		1.7	3	dB
	NF (2)	$V_{CE} = 3 \text{ V}, I_{C} = 7 \text{ mA}, f = 2 \text{ GHz}$		1.4	2.2	

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 5 V, I _E = 0	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	1	μΑ
DC current gain	h _{FE}	V _{CE} = 1 V, I _C = 5 mA	80	_	160	
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ (Not	e)	0.7	1.05	pF

Note: C_{re} is measured by 3 terminal method with capacitance bridge.

Caution

This device is sensitive to electrostatic discharge. Please handle with caution.



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